# MC74LVX14

# Hex Schmitt Inverter

## With 5 V−Tolerant Inputs

The MC74LVX14 is an advanced high speed CMOS Schmitt inverter. The inputs tolerate voltages up to 7 V, allowing the interface of 5 V systems to 3 V systems.

The MC74LVX14 is pin and functionally compatible to the MC74LVX04, but the inputs have hysteresis and, with its Schmitt trigger function, can be used as a line receiver which will receive slow input signals.

### Features

- High Speed: $t_{PD}$ = 6.8 ns (Typ) at $V_{CC}$ = 3.3 V
- Low Power Dissipation: $I_{CC}$ = 2 μA (Max) at $T_A$ = 25°C
- Powerdown Protection Provided on Inputs
- Balanced Propagation Delays
- Low Noise: $V_{OLP}$ = 0.5 V (Max)
- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 300 mA
- ESD Performance: Human Body Model > 2000 V;
  Machine Model > 200 V
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable
- These Devices are Pb−Free and are RoHS Compliant

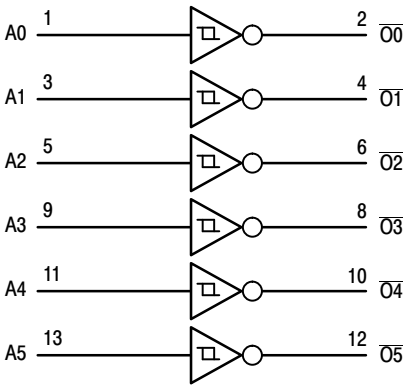



**Figure 1. Logic Diagram**

### PIN NAMES

| Pins | Function |
|---|---|
| An<br>On | Data Inputs<br>Data Outputs |

### FUNCTION TABLE

| An | On |
|---|---|
| L<br>H | H<br>L |

**ON Semiconductor®**

**http://onsemi.com**

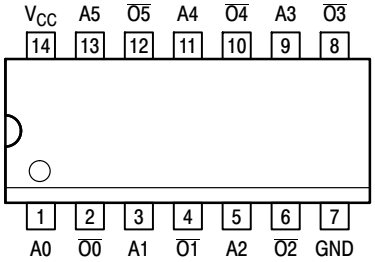


**SOIC−14 NB**
**D SUFFIX**
**CASE 751A**



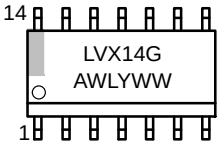
**TSSOP−14**
**DT SUFFIX**
**CASE 948G**

### PIN ASSIGNMENT

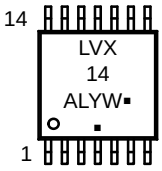



**14−Lead** (Top View)

### MARKING DIAGRAMS




**SOIC−14 NB**




**TSSOP−14**

LVX14 = Specific Device Code
A = Assembly Location
WL, L = Wafer Lot
Y = Year
WW, W = Work Week
G or ▪ = Pb−Free Package

(Note: Microdot may be in either location)

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

© Semiconductor Components Industries, LLC, 2014

## MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|---|---|---|---|
| $V_{CC}$ | DC Supply Voltage | –0.5 to +7.0 | V |
| $V_{in}$ | DC Input Voltage | –0.5 to +7.0 | V |
| $V_{out}$ | DC Output Voltage | –0.5 to $V_{CC}$ +0.5 | V |
| $I_{IK}$ | Input Diode Current | −20 | mA |
| $I_{OK}$ | Output Diode Current | ±20 | mA |
| $I_{out}$ | DC Output Current, per Pin | ±25 | mA |
| $I_{CC}$ | DC Supply Current, $V_{CC}$ and GND Pins | ±50 | mA |
| $P_D$ | Power Dissipation | 180 | mW |
| $T_{stg}$ | Storage Temperature | –65 to +150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

## RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Max | Unit |
|---|---|---|---|---|
| $V_{CC}$ | DC Supply Voltage | 2.0 | 3.6 | V |
| $V_{in}$ | DC Input Voltage | 0 | 5.5 | V |
| $V_{out}$ | DC Output Voltage | 0 | $V_{CC}$ | V |
| $T_A$ | Operating Temperature, All Package Types | −40 | +85 | °C |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

## DC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Test Conditions | $V_{CC}$ V | $T_A$ = 25°C | | | $T_A$ = −40 to 85°C | | Unit |
|---|---|---|---|---|---|---|---|---|---|
| | | | | Min | Typ | Max | Min | Max | |
| $V_{T+}$ | Positive Threshold Voltage (Figure 4) | | 3.0 | | | 2.20 | | 2.20 | V |
| $V_{T-}$ | Negative Threshold Voltage (Figure 4) | | 3.0 | 0.90 | | | 0.90 | | V |
| $V_H$ | Hysteresis Voltage (Figure 4) | | 3.0 | 0.30 | | 1.20 | 0.30 | 1.20 | V |
| $V_{OH}$ | High−Level Output Voltage ($V_{in}$ = $V_{IH}$ or $V_{IL}$) | $I_{OH}$ = −50 μA<br>$I_{OH}$ = −50 μA<br>$I_{OH}$ = −4 mA | 2.0<br>3.0<br>3.0 | 1.9<br>2.9<br>2.58 | 2.0<br>3.0 | | 1.9<br>2.9<br>2.48 | | V |
| $V_{OL}$ | Low−Level Output Voltage ($V_{in}$ = $V_{IH}$ or $V_{IL}$) | $I_{OL}$ = 50 μA<br>$I_{OL}$ = 50 μA<br>$I_{OL}$ = 4 mA | 2.0<br>3.0<br>3.0 | | 0.0<br>0.0 | 0.1<br>0.1<br>0.36 | | 0.1<br>0.1<br>0.44 | V |
| $I_{in}$ | Input Leakage Current | $V_{in}$ = 5.5 V or GND | 3.6 | | | ±0.1 | | ±1.0 | μA |
| $I_{CC}$ | Quiescent Supply Current | $V_{in}$ = $V_{CC}$ or GND | 3.6 | | | 2.0 | | 20.0 | μA |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## AC ELECTRICAL CHARACTERISTICS (Input $t_r$ = $t_f$ = 3.0 ns)

| Symbol | Parameter | Test Conditions | | $T_A$ = 25°C | | | $T_A$ = −40 to 85°C | | Unit |
|---|---|---|---|---|---|---|---|---|---|
| | | | | Min | Typ | Max | Min | Max | |
| $t_{PLH}$, $t_{PHL}$ | Propagation Delay, Input−to−Output | $V_{CC}$ = 2.7 V | $C_L$ = 15 pF<br>$C_L$ = 50 pF | | 8.7<br>11.2 | 16.3<br>19.8 | 1.0<br>1.0 | 19.5<br>23.0 | ns |
| | | $V_{CC}$ = 3.3 ± 0.3 V | $C_L$ = 15 pF<br>$C_L$ = 50 pF | | 6.8<br>9.3 | 10.6<br>14.1 | 1.0<br>1.0 | 12.5<br>16.0 | |
| $t_{OSHL}$<br>$t_{OSLH}$ | Output−to−Output Skew (Note 1) | $V_{CC}$ = 2.7 V<br>$V_{CC}$ = 3.3 ± 0.3 V | $C_L$ = 50 pF<br>$C_L$ = 50 pF | | | 1.5<br>1.5 | | 1.5<br>1.5 | ns |

1. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH−to−LOW ($t_{OSHL}$) or LOW−to−HIGH ($t_{OSLH}$); parameter guaranteed by design.

**CAPACITIVE CHARACTERISTICS**

| Symbol | Parameter | $T_A$ = 25°C | | | $T_A$ = −40 to 85°C | | Unit |
|---|---|---|---|---|---|---|---|
| | | Min | Typ | Max | Min | Max | |
| Cin | Input Capacitance | | 4 | 10 | | 10 | pF |
| $C_{PD}$ | Power Dissipation Capacitance (Note 2) | | 21 | | | | pF |

2. $C_{PD}$ is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}/6$ (per buffer). $C_{PD}$ is used to determine the no−load dynamic power consumption; $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.

**NOISE CHARACTERISTICS** (Input $t_r = t_f$ = 3.0 ns, $C_L$ = 50 pF, $V_{CC}$ = 3.3 V, Measured in SOIC Package)

| Symbol | Characteristic | $T_A$ = 25°C | | Unit |
|---|---|---|---|---|
| | | Typ | Max | |
| $V_{OLP}$ | Quiet Output Maximum Dynamic $V_{OL}$ | 0.3 | 0.5 | V |
| $V_{OLV}$ | Quiet Output Minimum Dynamic $V_{OL}$ | −0.3 | −0.5 | V |
| $V_{IHD}$ | Minimum High Level Dynamic Input Voltage | | 2.0 | V |
| $V_{ILD}$ | Maximum Low Level Dynamic Input Voltage | | 0.9 | V |

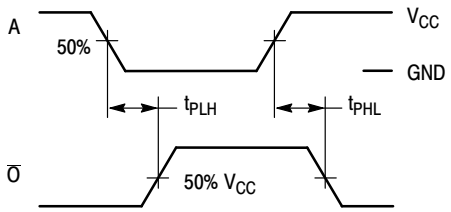
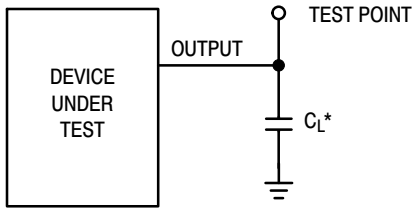



**Figure 2. Switching Waveforms**




*Includes all probe and jig capacitance

**Figure 3. Test Circuit**

**ORDERING INFORMATION**

| Device | Package | Shipping† |
|---|---|---|
| MC74LVX14DR2G | SOIC−14 NB (Pb−Free) | 2500 Tape & Reel |
| MC74LVX14DTR2G | TSSOP−14 (Pb−Free) | 2500 Tape & Reel |
| NLV74LVX14DTR2G* | TSSOP−14 (Pb−Free) | 2500 Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable.

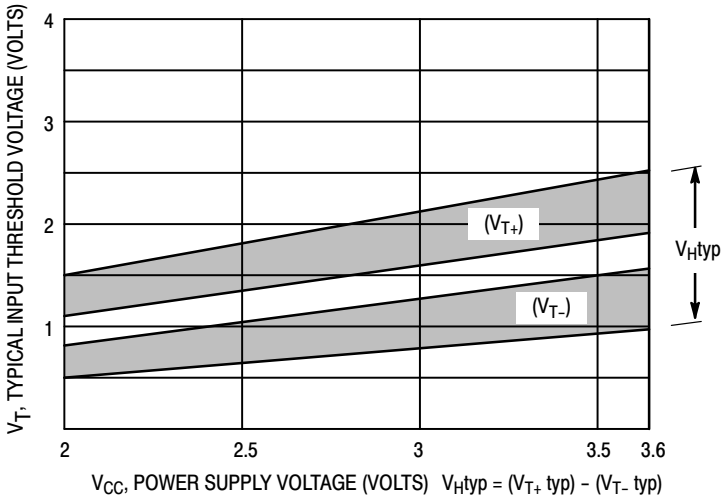
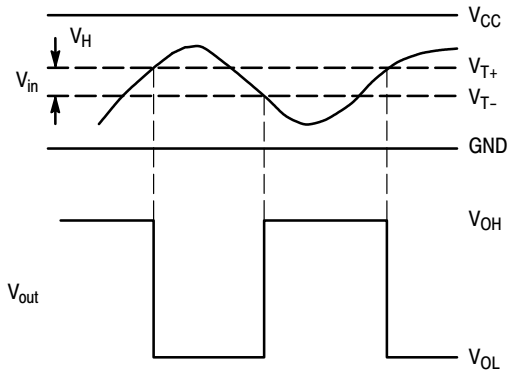
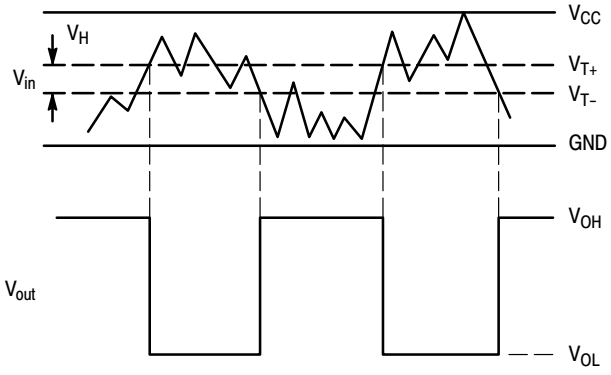



**Figure 4. Typical Input Threshold, $V_{T+}$, $V_{T-}$ versus Power Supply Voltage**



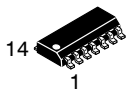

(a) A Schmitt−Trigger Squares Up Inputs With Slow Rise and Fall Times




(b) A Schmitt−Trigger Offers Maximum Noise Immunity

**Figure 5. Typical Schmitt−Trigger Applications**

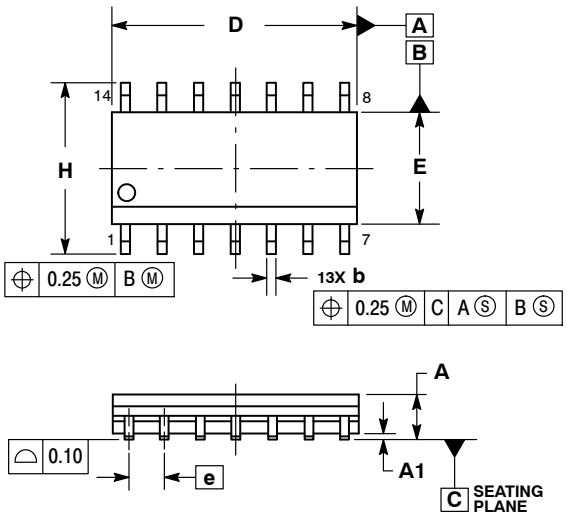
# MECHANICAL CASE OUTLINE
## PACKAGE DIMENSIONS

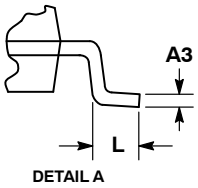


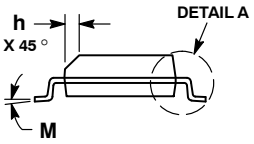

**SCALE 1:1**

**SOIC−14 NB**
CASE 751A−03
ISSUE L

DATE 03 FEB 2016



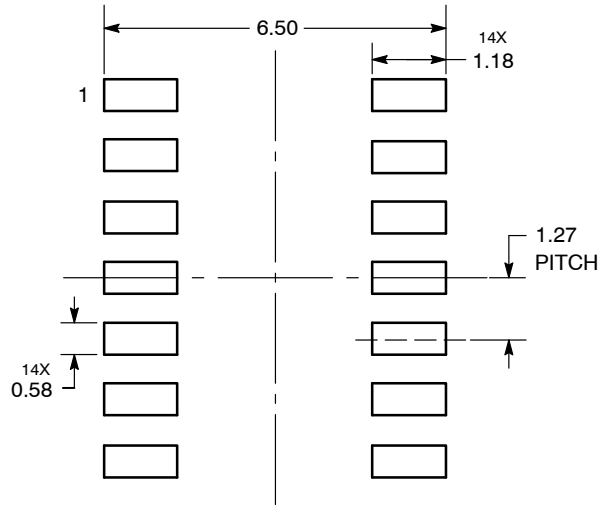




NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT MAXIMUM MATERIAL CONDITION.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

| | MILLIMETERS | | INCHES | |
|---|---|---|---|---|
| DIM | MIN | MAX | MIN | MAX |
| A | 1.35 | 1.75 | 0.054 | 0.068 |
| A1 | 0.10 | 0.25 | 0.004 | 0.010 |
| A3 | 0.19 | 0.25 | 0.008 | 0.010 |
| b | 0.35 | 0.49 | 0.014 | 0.019 |
| D | 8.55 | 8.75 | 0.337 | 0.344 |
| E | 3.80 | 4.00 | 0.150 | 0.157 |
| e | 1.27 BSC | | 0.050 BSC | |
| H | 5.80 | 6.20 | 0.228 | 0.244 |
| h | 0.25 | 0.50 | 0.010 | 0.019 |
| L | 0.40 | 1.25 | 0.016 | 0.049 |
| M | 0 ° | 7 ° | 0 ° | 7 ° |

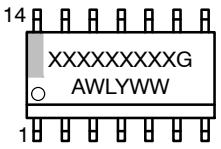
### SOLDERING FOOTPRINT*




DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### GENERIC MARKING DIAGRAM*




XXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
Y = Year
WW = Work Week
G = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

**STYLES ON PAGE 2**

| | | | |
|---|---|---|---|
| **DOCUMENT NUMBER:** | **98ASB42565B** | Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped “CONTROLLED COPY” in red. | |
| **DESCRIPTION:** | **SOIC−14 NB** | | **PAGE 1 OF 2** |

**onsemi** and onsemi are trademarks of Semiconductor Components Industries, LLC dba **onsemi** or its subsidiaries in the United States and/or other countries. **onsemi** reserves the right to make changes without further notice to any products herein. **onsemi** makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. **onsemi** does not convey any license under its patent rights nor the rights of others.

© Semiconductor Components Industries, LLC, 2019

**SOIC−14**
CASE 751A−03
ISSUE L

DATE 03 FEB 2016

STYLE 1:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. NO CONNECTION
5. ANODE/CATHODE
6. NO CONNECTION
7. ANODE/CATHODE
8. ANODE/CATHODE
9. ANODE/CATHODE
10. NO CONNECTION
11. ANODE/CATHODE
12. ANODE/CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 2:
CANCELLED

STYLE 3:
PIN 1. NO CONNECTION
2. ANODE
3. ANODE
4. NO CONNECTION
5. ANODE
6. NO CONNECTION
7. ANODE
8. ANODE
9. ANODE
10. NO CONNECTION
11. ANODE
12. ANODE
13. NO CONNECTION
14. COMMON CATHODE

STYLE 4:
PIN 1. NO CONNECTION
2. CATHODE
3. CATHODE
4. NO CONNECTION
5. CATHODE
6. NO CONNECTION
7. CATHODE
8. CATHODE
9. CATHODE
10. NO CONNECTION
11. CATHODE
12. CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 5:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. ANODE/CATHODE
5. ANODE/CATHODE
6. NO CONNECTION
7. COMMON ANODE
8. COMMON CATHODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. ANODE/CATHODE
12. ANODE/CATHODE
13. NO CONNECTION
14. COMMON ANODE

STYLE 6:
PIN 1. CATHODE
2. CATHODE
3. CATHODE
4. CATHODE
5. CATHODE
6. CATHODE
7. CATHODE
8. ANODE
9. ANODE
10. ANODE
11. ANODE
12. ANODE
13. ANODE
14. ANODE

STYLE 7:
PIN 1. ANODE/CATHODE
2. COMMON ANODE
3. COMMON CATHODE
4. ANODE/CATHODE
5. ANODE/CATHODE
6. ANODE/CATHODE
7. ANODE/CATHODE
8. ANODE/CATHODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. COMMON CATHODE
12. COMMON ANODE
13. ANODE/CATHODE
14. ANODE/CATHODE

STYLE 8:
PIN 1. COMMON CATHODE
2. ANODE/CATHODE
3. ANODE/CATHODE
4. NO CONNECTION
5. ANODE/CATHODE
6. ANODE/CATHODE
7. COMMON ANODE
8. COMMON ANODE
9. ANODE/CATHODE
10. ANODE/CATHODE
11. NO CONNECTION
12. ANODE/CATHODE
13. ANODE/CATHODE
14. COMMON CATHODE



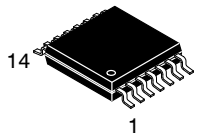

**onsemi** and ONSEMI. are trademarks of Semiconductor Components Industries, LLC dba **onsemi** or its subsidiaries in the United States and/or other countries. **onsemi** reserves the right to make changes without further notice to any products herein. **onsemi** makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. **onsemi** does not convey any license under its patent rights nor the rights of others.

© Semiconductor Components Industries, LLC, 2019

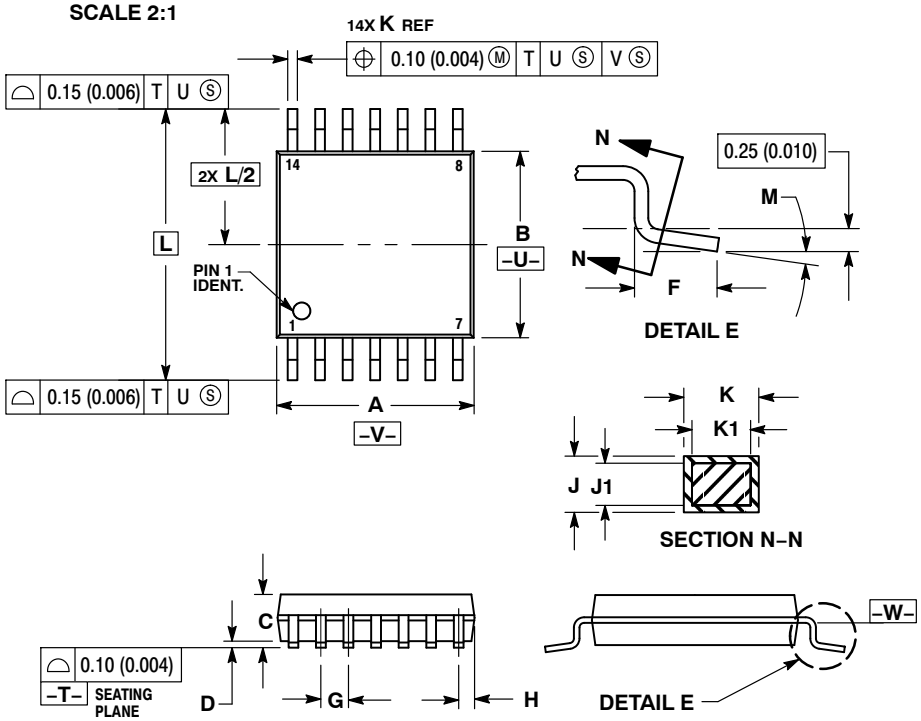
# MECHANICAL CASE OUTLINE
## PACKAGE DIMENSIONS

**TSSOP−14 WB**
CASE 948G
ISSUE C

DATE 17 FEB 2016



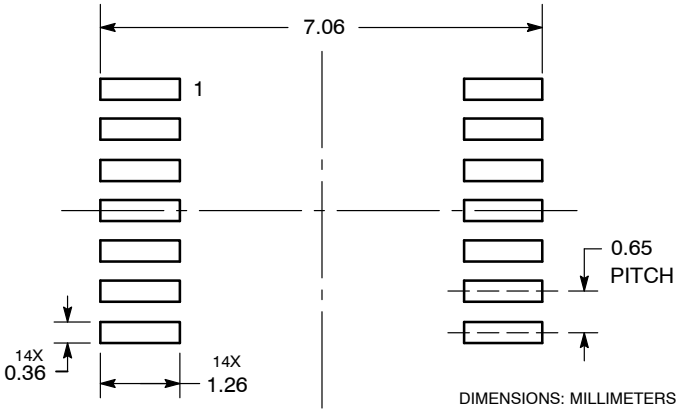

**SCALE 2:1**




NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE −W−.

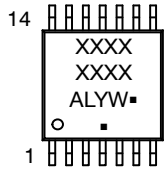
| | MILLIMETERS | | INCHES | |
|---|---|---|---|---|
| DIM | MIN | MAX | MIN | MAX |
| A | 4.90 | 5.10 | 0.193 | 0.200 |
| B | 4.30 | 4.50 | 0.169 | 0.177 |
| C | −−− | 1.20 | −−− | 0.047 |
| D | 0.05 | 0.15 | 0.002 | 0.006 |
| F | 0.50 | 0.75 | 0.020 | 0.030 |
| G | 0.65 BSC | | 0.026 BSC | |
| H | 0.50 | 0.60 | 0.020 | 0.024 |
| J | 0.09 | 0.20 | 0.004 | 0.008 |
| J1 | 0.09 | 0.16 | 0.004 | 0.006 |
| K | 0.19 | 0.30 | 0.007 | 0.012 |
| K1 | 0.19 | 0.25 | 0.007 | 0.010 |
| L | 6.40 BSC | | 0.252 BSC | |
| M | 0 ° | 8 ° | 0 ° | 8 ° |

### SOLDERING FOOTPRINT




DIMENSIONS: MILLIMETERS

### GENERIC MARKING DIAGRAM*




A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
▪ = Pb−Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

| | | |
|---|---|---|
| **DOCUMENT NUMBER:** | **98ASH70246A** | Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped “CONTROLLED COPY” in red. |
| **DESCRIPTION:** | **TSSOP−14 WB** | **PAGE 1 OF 1** |

**onsemi** and onsemi are trademarks of Semiconductor Components Industries, LLC dba **onsemi** or its subsidiaries in the United States and/or other countries. **onsemi** reserves the right to make changes without further notice to any products herein. **onsemi** makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. **onsemi** does not convey any license under its patent rights nor the rights of others.

© Semiconductor Components Industries, LLC, 2019

**onsemi**, ONSEMI , and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent−Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as−is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## PUBLICATION ORDERING INFORMATION

**LITERATURE FULFILLMENT**:
**Email Requests to:** orderlit@onsemi.com

**onsemi Website:** www.onsemi.com

**TECHNICAL SUPPORT**
**North American Technical Support:**
Voice Mail: 1 800−282−9855 Toll Free USA/Canada
Phone: 011 421 33 790 2910

**Europe, Middle East and Africa Technical Support:**
Phone: 00421 33 790 2910
For additional information, please contact your local Sales Representative

◊